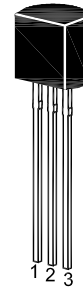


MPS8599

PNP Silicon Amplifier Transistor

On special request, these transistors can be manufactured in different pin configurations.



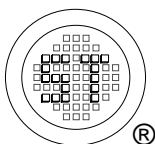
1. Emitter 2. Base 3. Collector
TO-92 Plastic Package

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	80	V
Collector Emitter Voltage	$-V_{CEO}$	80	V
Emitter Base Voltage	$-V_{EBO}$	5	V
Collector Current	$-I_C$	500	mA
Power Dissipation	P_{tot}	625	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain					
at $-V_{CE} = 5\text{ V}$, $-I_C = 1\text{ mA}$	h_{FE}	100	-	300	-
at $-V_{CE} = 5\text{ V}$, $-I_C = 10\text{ mA}$	h_{FE}	100	-	-	-
at $-V_{CE} = 5\text{ V}$, $-I_C = 100\text{ mA}$	h_{FE}	75	-	-	-
Collector Base Cutoff Current					
at $-V_{CB} = 80\text{ V}$	$-I_{CBO}$	-	-	0.1	μA
Collector Emitter Cutoff Current					
at $-V_{CE} = 60\text{ V}$	$-I_{CES}$	-	-	0.1	μA
Emitter Base Cutoff Current					
at $-V_{EB} = 4\text{ V}$	$-I_{EBO}$	-	-	0.1	μA
Collector Base Breakdown Voltage					
at $-I_C = 100\text{ }\mu\text{A}$	$-V_{(BR)CBO}$	80	-	-	V
Collector Emitter Breakdown Voltage					
at $-I_C = 10\text{ mA}$	$-V_{(BR)CEO}$	80	-	-	V
Emitter-Base Breakdown Voltage					
at $-I_E = 10\text{ }\mu\text{A}$	$-V_{(BR)EBO}$	5	-	-	V
Collector Emitter Saturation Voltage					
at $-I_C = 100\text{ mA}$, $-I_B = 5\text{ mA}$	$-V_{CEsat}$	-	-	0.4	V
at $-I_C = 100\text{ mA}$, $-I_B = 10\text{ mA}$	$-V_{CEsat}$	-	-	0.3	V
Base Emitter On Voltage					
at $-V_{CE} = 5\text{ V}$, $-I_C = 10\text{ mA}$	$-V_{BE(on)}$	0.6	-	0.8	V
Current Gain Bandwidth Product					
at $-V_{CE} = 5\text{ V}$, $-I_C = 10\text{ mA}$, $f = 100\text{ MHz}$	f_T	150	-	-	MHz
Output Capacitance					
at $-V_{CB} = 5\text{ V}$, $f = 1\text{ MHz}$	C_{obo}	-	-	8	pF

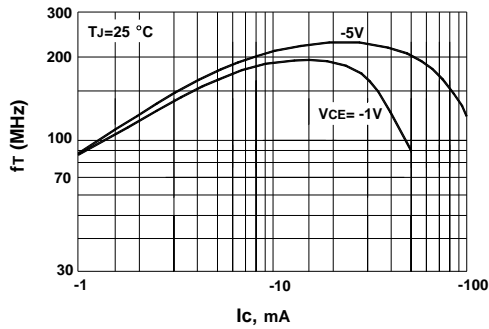


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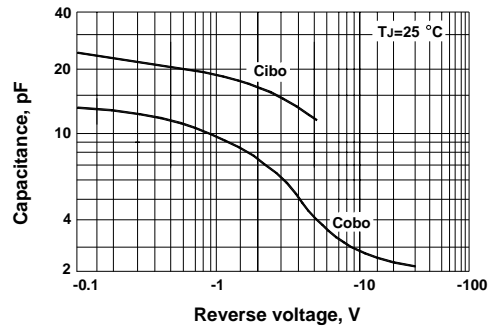


Dated : 24/06/2003

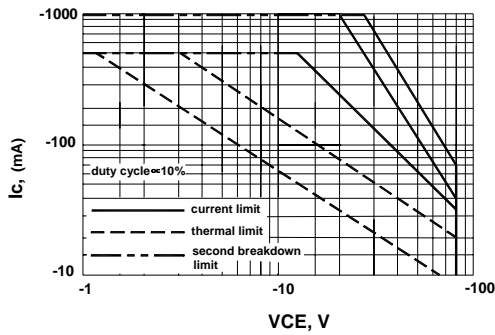
Current gain - bandwidth product



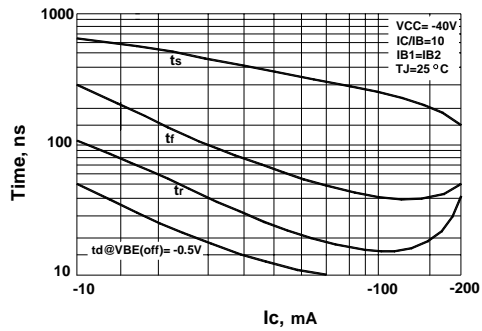
Capacitance



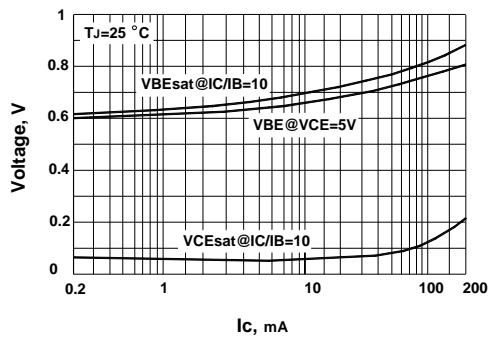
Active - region safe operating area



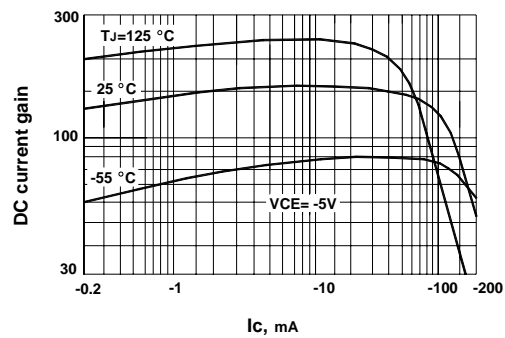
Switching times



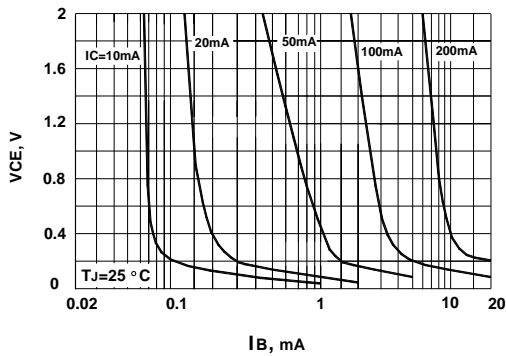
"ON" Voltages



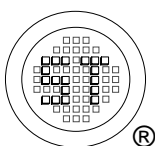
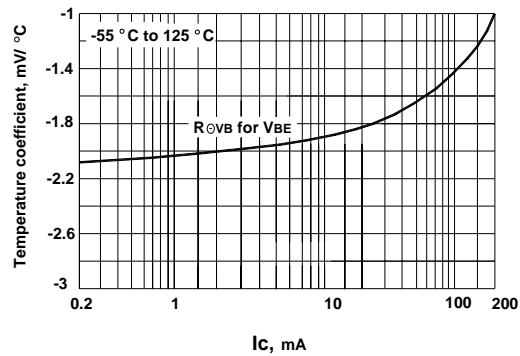
DC current gain



Collector saturation region



Base emitter temperature coefficient



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